SLLS206H - MAY 1995 - REVISED JUNE 2002

- Single Chip With Easy Interface Between UART and Serial-Port Connector of IBM[™] PC/AT and Compatibles
- Meet or Exceed the Requirements of ANSI Standard TIA/EIA-232-F and ITU Recommendation V.28
- Designed to Support Data Rates up to 120 kbit/s
- Pinout Compatible With SN75C185 and SN75185

,	DB, DW, N, OR PW PACKAGE PP VIEW)
V _{DD} [1	20] V _{CC}
RA1 [2	19] RY1
RA2 [3	18] RY2
RA3 [4	17] RY3
DY1 [5	16] DA1
DY2 [6	15] DA2
RA4 [7	14] RY4
DY3 [8	13] DA3
RA5 [9	12] RY5
V _{SS} [10	11] GND

description

The GD65232 and GD75232 combine three drivers and five receivers from the Texas Instruments trade-standard SN75188 and SN75189 bipolar quadruple drivers and receivers, respectively. The pinout matches the flow-through design of the SN75C185 to decrease the part count, reduce the board space required, and allow easy interconnection of the UART and serial-port connector of an IBM[™] PC/AT and compatibles. The bipolar circuits and processing of the GD65232 and GD75232 provide a rugged, low-cost solution for this function at the expense of quiescent power and external passive components relative to the SN75C185.

The GD65232 and GD75232 comply with the requirements of the TIA/EIA-232-F and ITU (formerly CCITT) V.28 standards. These standards are for data interchange between a host computer and a peripheral at signaling rates up to 20 kbit/s. The switching speeds of these devices are fast enough to support rates up to 120 kbit/s with lower capacitive loads (shorter cables). Interoperability at the higher signaling rates cannot be expected unless the designer has design control of the cable and the interface circuits at both ends. For interoperability at signaling rates up to 120 kbit/s, use of ANSI TIA/EIA-423-B (ITU V.10) and TIA/EIA-422-B (ITU V.11) standards is recommended.

TA	PACKAG	GE†	ORDERABLE PART NUMBER	TOP-SIDE MARKING
	PDIP – N Tube GD65232N GD6523		GD65232N	
	SOIC - DW	Tube	GD65232DW	GD65232
–40°C to 85°C	3010 - 010	Tape and reel	GD65232DWR	GD05252
	SSOP – DB	Tape and reel	GD65232DBR	GD65232
	TSSOP – PW	Tape and reel	GD65232PWR	GD65232
	PDIP – N	Tube	GD75232N	GD75232N
	SOIC - DW	Tube	GD75232DW	GD75232
0°C to 70°C	3010 - 010	Tape and reel	GD75232DWR	GD75252
	SSOP – DB	Tape and reel	GD75232DBR	GD75232
	TSSOP – PW	Tape and reel	GD75232PWR	GD75232

ORDERING INFORMATION

[†] Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.



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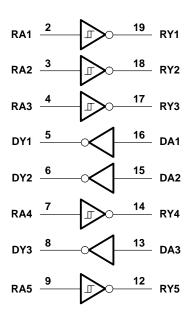
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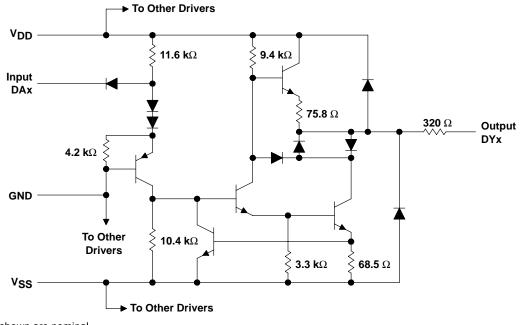


SLLS206H - MAY 1995 - REVISED JUNE 2002

logic diagram (positive logic)



schematic (each driver)

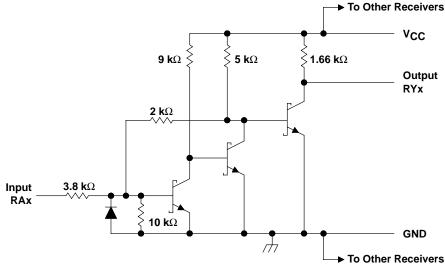


Resistor values shown are nominal.



SLLS206H - MAY 1995 - REVISED JUNE 2002

schematic (each receiver)



Resistor values shown are nominal.

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)[†]

Supply voltage (see Note 1): V _{CC}	10 V
	45.V
V _{DD}	
V _{SS}	–15 V
Input voltage range, V _I : Driver	–15 V to 7 V
Receiver	–30 V to 30 V
Driver output voltage range, V _O	
Receiver low-level output current, IOL	
Package thermal impedance, θ_{JA} (see Note 2): DB package	
	58°C/W
N package	69°C/W
PW package	
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds	260°C
Storage temperature range, T _{stg}	

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. All voltages are with respect to the network ground terminal.

2. The package thermal impedance is calculated in accordance with JESD 51-7.



SLLS206H - MAY 1995 - REVISED JUNE 2002

recommended operating conditions

			MIN	NOM	MAX	UNIT
V _{DD}	Supply voltage (see Note 3)		7.5	9	15	V
VSS	V _{SS} Supply voltage (see Note 3)				-15	V
VCC	Supply voltage (see Note 3)		4.5	5	5.5	V
VIH	High-level input voltage (driver only)		1.9			V
VIL	Low-level input voltage (driver only)				0.8	V
1		river			-6	~
ЮН	High-level output current Re	eceiver			-0.5	mA
1		river			6	mA
IOL	Low-level output current Re	eceiver			16	mA
TA	Operating free-air temperature	D65232	-40		85	°C
	GD75232		0		70	0

NOTE 3: When powering up the GD65232 and GD75232, the following sequence should be used:

1. V_{SS} 2. GND

3. V_{DD}

4. VCC

5. I/Os

Applying V_{CC} to the device before V_{DD} may allow large currents to flow, causing damage to the device. When powering down the GD65232 and GD75232, the reverse sequence should be used.

supply currents over recommended operating free-air temperature range

	PARAMETER	TEST CONDITIONS VDD = 9 V. VSS = -9 V				MIN N	ЛАХ	UNIT				
				V _{DD} = 9 V,	$V_{SS} = -9 V$		15					
		All inputs at 1.9 V,	No load	V _{DD} = 12 V,	$V_{SS} = -12 V$		19					
100	Supply current from V			V _{DD} = 15 V,	V _{SS} = -15 V		25	mA				
IDD				V _{DD} = 9 V,	$V_{SS} = -9 V$		4.5	ШA				
		All inputs at 0.8 V,	No load	V _{DD} = 12 V,	$V_{SS} = -12 V$		5.5					
				V _{DD} = 15 V,	V _{SS} = -15 V		9					
				V _{DD} = 9 V,	$V_{SS} = -9 V$		-15					
		All inputs at 1.9 V,	All inputs at 1.9 V,	All inputs at 1.9 V,	All inputs at 1.9 V,	All inputs at 1.9 V,	No load	V _{DD} = 12 V,	$V_{SS} = -12 V$		-19	
100	Supply current from VSS			V _{DD} = 15 V,	V _{SS} = -15 V		-25	mA				
ISS	Supply current norm vSS			V _{DD} = 9 V,	$V_{SS} = -9 V$	-	-3.2	ШA				
		All inputs at 0.8 V,	No load	V _{DD} = 12 V,	$V_{SS} = -12 V$	-	-3.2					
				V _{DD} = 15 V,	$V_{SS} = -15 V$	-	-3.2					
100			V _{CC} = 5 V	GD65232		38	mA					
lcc	Supply current from V _{CC}	All inputs at 5 V,	No load,	•CC = 2 v	GD75232		30	IIIA				



SLLS206H - MAY 1995 - REVISED JUNE 2002

DRIVER SECTION

electrical characteristics over recommended operating free-air temperature range, V_{DD} = 9 V, V_{SS} = -9 V, V_{CC} = 5 V (unless otherwise noted)

	PARAMETER	TEST CONDITIONS			MIN	TYP	MAX	UNIT
VOH	High-level output voltage	V _{IL} = 0.8 V,	$R_L = 3 k\Omega$,	See Figure 1	6	7.5		V
VOL	Low-level output voltage (see Note 4)	V _{IH} = 1.9 V,	$R_L = 3 k\Omega$,	See Figure 1		-7.5	-6	V
ЧΗ	High-level input current	V _I = 5 V,	See Figure 2				10	μA
۱ _{IL}	Low-level input current	$V_{I} = 0,$	See Figure 2				-1.6	mA
IOS(H)	High-level short-circuit output current (see Note 5)	V _{IL} = 0.8 V,	$V_{O} = 0,$	See Figure 1	-4.5	-12	-19.5	mA
IOS(L)	Low-level short-circuit output current	V _{IH} = 2 V,	$V_{O} = 0,$	See Figure 1	4.5	12	19.5	mA
r _o	Output resistance (see Note 6)	$V_{CC} = V_{DD} =$	$V_{SS} = 0$,	$V_{O} = -2 V$ to 2 V	300			Ω

NOTES: 4. The algebraic convention, where the more positive (less negative) limit is designated as maximum, is used in this data sheet for logic levels only (e.g., if –10 V is maximum, the typical value is a more negative voltage).

5. Output short-circuit conditions must maintain the total power dissipation below absolute maximum ratings.

6. Test conditions are those specified by TIA/EIA-232-F and as listed above.

switching characteristics, V_{CC} = 5 V, V_{DD} = 12 V, V_{SS} = -12 V, T_A = 25° C

	PARAMETER	TEST CONDITIONS			MIN TYP MAX			UNIT
^t PLH	Propagation delay time, low- to high-level output	$R_L = 3 k\Omega$ to 7 kΩ,	C _L = 15 pF,	See Figure 3		315	500	ns
^t PHL	Propagation delay time, high- to low-level output	$R_L = 3 k\Omega$ to 7 k Ω ,	C _L = 15 pF,	See Figure 3		75	175	ns
+	Transition time,	$R_{I} = 3 k\Omega \text{ to } 7 k\Omega$	C _L = 15 pF,	See Figure 3		60	100	ns
^t TLH	low- to high-level output	$K_{L} = 3 K_{22} 10 7 K_{22}$	C _L = 2500 pF,	See Figure 3 and Note 7		1.7	2.5	μs
	Transition time,	$B_{1} = 2 k_{0} t_{0} T_{k_{0}}$	C _L = 15 pF,	See Figure 3		40	75	ns
^t THL	high- to low-level output	$R_L = 3 k\Omega$ to 7 k Ω	C _L = 2500 pF,	See Figure 3 and Note 7		1.5	2.5	μs

NOTE 7: Measured between ±3-V and ±3-V points of the output waveform (TIA/EIA-232-F conditions); all unused inputs are tied either high or low.



SLLS206H - MAY 1995 - REVISED JUNE 2002

RECEIVER SECTION

electrical characteristics over recommended operating conditions (unless otherwise noted)

	PARAMETER	TEST CONDITIONS			MIN	TYP†	MAX	UNIT	
\/		T _A = 25°C,	See Figure 5		1.75	1.9	2.3	V	
VIT+	Positive-going input threshold voltage	$T_A = 0^{\circ}C$ to $70^{\circ}C$,	See Figure 5		1.55		2.3	v	
V _{IT} _	Negative-going input threshold voltage				0.75	0.97	1.25	V	
V _{hys}	Input hysteresis voltage (V _{IT+} – V _{IT–})				0.5			V	
Varia	Link lovel output voltogo	1au 0.5 mA	V _{IH} = 0.75 V		2.6	4	5	V	
Vон	High-level output voltage	I _{OH} = -0.5 mA	Inputs open		2.6			v	
VOL	Low-level input voltage	I _{OL} = 10 mA,	V _I = 3 V			0.2	0.45	V	
				GD65232	3.6		11		
Iн	High-level input current	$v_{1} = 25 v_{2}$	V _I = 25 V,	See Figure 5	GD75232	3.6		8.3	mA
		V _I = 3 V,	See Figure 5		0.43				
				GD65232	-3.6		-11		
۱ _{IL}	Low-level output current	V _I = -25 V,	See Figure 5	GD75232	-3.6		-8.3	mA	
		$V_{ } = -3 V,$	See Figure 5	-	-0.43				
IOS	Short-circuit output current	See Figure 4				-3.4	-12	mA	

[†] All typical values are at $T_A = 25^{\circ}C$, $V_{CC} = 5$ V, $V_{DD} = 9$ V, and $V_{SS} = -9$ V.

switching characteristics, V_{CC} = 5 V, V_{DD} = 12 V, V_{SS} = –12 V, T_A = 25°C

PARAMETER		TEST CONDITIONS			MIN	TYP	MAX	UNIT
^t PLH	Propagation delay time, low- to high-level output					107	250	ns
^t PHL	Propagation delay time, high- to low-level output	C _L = 50 pF,	$R_1 = 5 k\Omega$,	See Figure 6		42	150	ns
^t TLH	Transition time, low- to high-level output		$R_{L} = 5 \text{ Ks2},$			175	350	ns
^t THL	Transition time, high- to low-level output					16	60	ns
^t PLH	Propagation delay time, low- to high-level output					100	160	ns
^t PHL	Propagation delay time, high- to low-level output	C 15 pE	$\mathbf{P}_{\mathbf{k}} = 1 \mathbf{E} \mathbf{k} 0$			60	100	ns
^t TLH	Transition time, low- to high-level output	C _L = 15 pF,	$R_{L} = 1.5 \text{ ks}_{2}$	See Figure 6		90	175	ns
^t THL	Transition time, high- to low-level output					15	50	ns



SLLS206H - MAY 1995 - REVISED JUNE 2002

PARAMETER MEASUREMENT INFORMATION

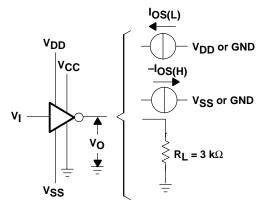


Figure 1. Driver Test Circuit for V_{OH}, V_{OL}, I_{OS(H)}, and I_{OS(L)}

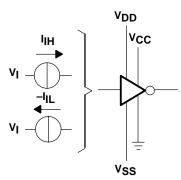
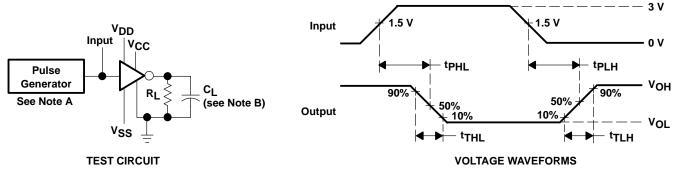
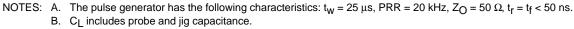


Figure 2. Driver Test Circuit for IIH and IIL









SLLS206H - MAY 1995 - REVISED JUNE 2002

PARAMETER MEASUREMENT INFORMATION

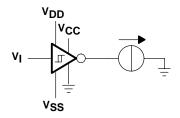


Figure 4. Receiver Test Circuit for IOS

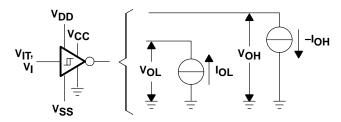
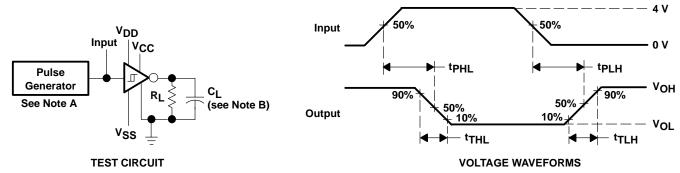


Figure 5. Receiver Test Circuit for V_{IT} , V_{OH} , and V_{OL}



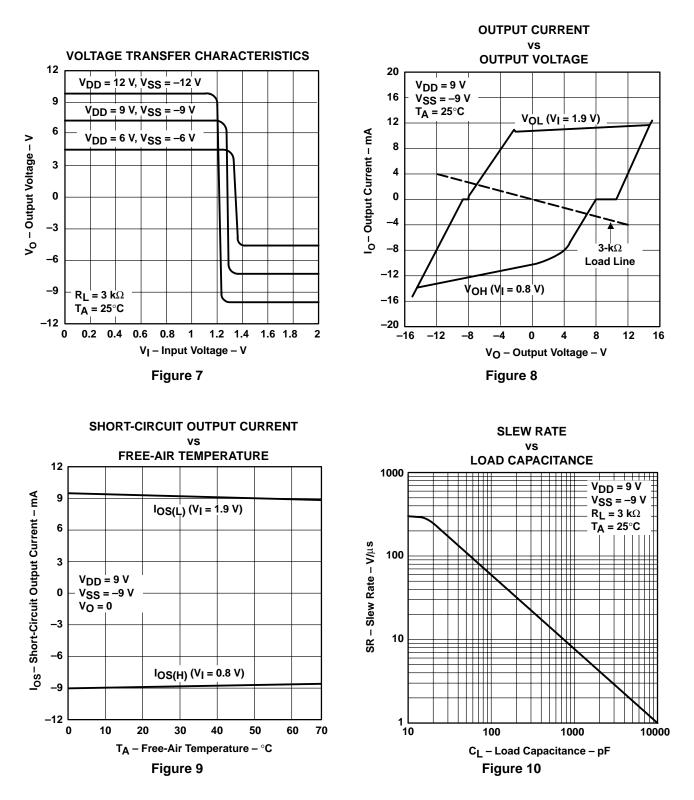
NOTES: A. The pulse generator has the following characteristics: $t_W = 25 \ \mu$ s, PRR = 20 kHz, $Z_O = 50 \ \Omega$, $t_f = t_f < 50 \ ns$. B. CL includes probe and jig capacitance.

Figure 6. Receiver Propagation and Transition Times



SLLS206H - MAY 1995 - REVISED JUNE 2002

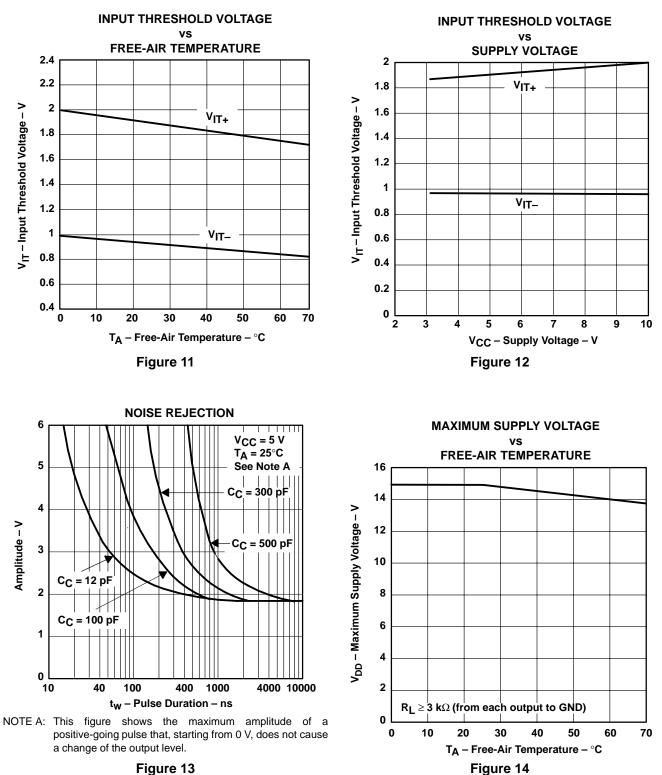
TYPICAL CHARACTERISTICS



DRIVER SECTION



SLLS206H - MAY 1995 - REVISED JUNE 2002



TYPICAL CHARACTERISTICS

Figure 13



SLLS206H - MAY 1995 - REVISED JUNE 2002

APPLICATION INFORMATION

Diodes placed in series with the V_{DD} and V_{SS} leads protect the GD65232 and GD75232 in the fault condition in which the device outputs are shorted to ± 15 V and the power supplies are at low and provide low-impedance paths to ground (see Figure 15).

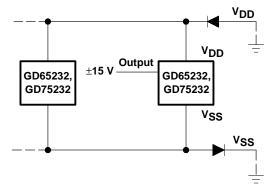


Figure 15. Power-Supply Protection to Meet Power-Off Fault Conditions of TIA/EIA-232-F

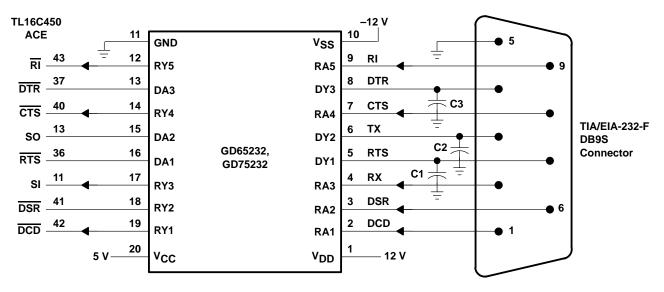


Figure 16. Typical Connection



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